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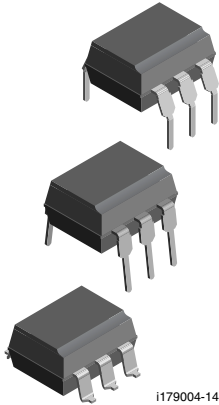


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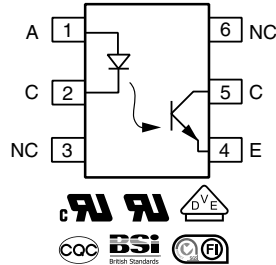
CNY17F

Vishay Semiconductors

Optocoupler, Phototransistor Output, no Base Connection



i179004-14



FEATURES

- Isolation test voltage, 5000 V_{RMS}
- No base terminal connection for improved common mode interface immunity
- Long term stability
- Industry standard dual-in-line package
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

AGENCY APPROVALS

Safety application model number covering all products in this datasheet is CNY17F. This model number should be used when consulting safety agency documents.

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065, EN 60950-1
- FIMKO EN60950
- CQC GB8898-2011

DESCRIPTION

The CNY17F is an optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled is not allowed to exceed the maximum permissible reference voltages.

In contrast to the CNY17 series, the base terminal of the F type is not connected, resulting in a substantially improved common-mode interference immunity.

ORDERING INFORMATION																
C	N	Y	1	7	F	-	#	X	0	#	#	T	DIP-6 7.62 mm	Option 6 10.16 mm	Option 7 > 8 mm	Option 9 8 mm typ.
PART NUMBER							CTR BIN	PACKAGE OPTION			TAPE AND REEL					
AGENCY CERTIFIED/PACKAGE		CTR (%)														
UL, cUL, BSI, FIMKO		40 to 80	63 to 125	100 to 200	160 to 320											
DIP-6		CNY17F-1	CNY17F-2	CNY17F-3	CNY17F-4											
DIP-6, 400 mil, option 6		CNY17F-1X006	CNY17F-2X006	CNY17F-3X006	CNY17F-4X006											
SMD-6, option 7		CNY17F-1X007 ⁽¹⁾	CNY17F-2X007T ⁽¹⁾	CNY17F-3X007T ⁽¹⁾	CNY17F-4X007T ⁽¹⁾											
SMD-6, option 9		CNY17F-1X009T ⁽¹⁾	CNY17F-2X009T ⁽¹⁾	CNY17F-3X009T ⁽¹⁾	CNY17F-4X009T ⁽¹⁾											
VDE, UL, cUL, BSI, FIMKO		40 to 80	63 to 125	100 to 200	160 to 320											
DIP-6		CNY17F-1X001	CNY17F-2X001	CNY17F-3X001	CNY17F-4X001											
DIP-6, 400 mil, option 6		CNY17F-1X016	CNY17F-2X016	CNY17F-3X016	CNY17F-4X016											
SMD-6, option 7		CNY17F-1X017 ⁽¹⁾	CNY17F-2X017 ⁽¹⁾	CNY17F-3X017 ⁽¹⁾	CNY17F-4X017 ⁽¹⁾											
SMD-6, option 9		CNY17F-1X019	CNY17F-2X019 ⁽¹⁾	CNY17F-3X019 ⁽¹⁾	-											

Notes

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not put T on end.



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
DC forward current		I _F	60	mA
Surge forward current	t ≤ 10 μs	I _{FSM}	2.5	A
Power dissipation		P _{diss}	100	mW
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	70	V
Collector current		I _C	50	mA
Collector peak current	t _p /T = 0.5, t _p ≤ 10 ms	I _{CM}	100	mA
Output power dissipation		P _{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector	t = 1 min	V _{ISO}	5000	V _{RMS}
Storage temperature range		T _{stg}	-55 to +150	°C
Ambient temperature range		T _{amb}	-55 to +110	°C
Junction temperature		T _j	100	°C
Soldering temperature ⁽¹⁾	2 mm from case, ≤ 10 s	T _{slid}	260	°C
Total power dissipation		P _{diss}	250	mW

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted parts (SMD). Refer to wave profile for soldering conditions for through hole parts (DIP).

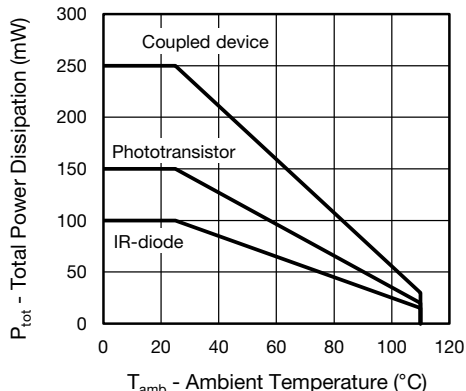


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F		1.39	1.65	V
Breakdown voltage	I _R = 10 μA		V _{BR}	6			V
Reverse current	V _R = 6 V		I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		C _O		25		pF
OUTPUT							
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		5.2		pF
Base collector capacitance	V _{CE} = 5 V, f = 1 MHz		C _{BC}		6.5		pF
Emitter base capacitance	V _{CE} = 5 V, f = 1 MHz		C _{EB}		7.5		pF



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER							
Collector emitter, saturation voltage	$I_F = 10\text{ mA}$, $I_C = 2.5\text{ mA}$		V_{CEsat}		0.25	0.4	V
Coupling capacitance			C_C		0.6		pF
Collector emitter, leakage current	$V_{CE} = 10\text{ V}$	CNY17F-1	I_{CEO}		2	50	nA
		CNY17F-2	I_{CEO}		2	50	nA
		CNY17F-3	I_{CEO}		5	100	nA
		CNY17F-4	I_{CEO}		5	100	nA

Note

- Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 10\text{ mA}$	CNY17F-1	CTR	40		80	%
		CNY17F-2	CTR	63		125	%
		CNY17F-3	CTR	100		200	%
		CNY17F-4	CTR	160		320	%
	$I_F = 1\text{ mA}$	CNY17F-1	CTR	13	30		%
		CNY17F-2	CTR	22	45		%
		CNY17F-3	CTR	34	70		%
		CNY17F-4	CTR	56	90		%

Note

- Current transfer ratio I_C/I_F at $V_{CE} = 5\text{ V}$, $25\text{ }^{\circ}\text{C}$ and collector emitter leakage current by dash number.

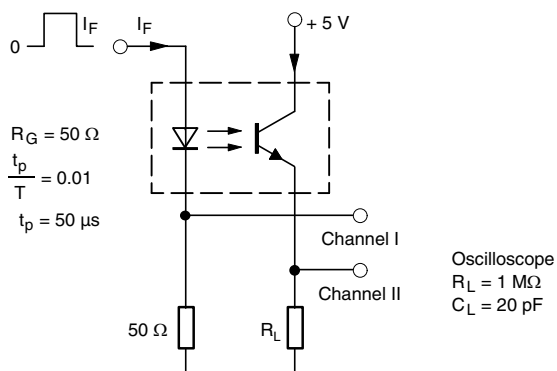
SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
LINEAR OPERATION (without saturation)							
Turn-on time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{on}		3		μs
Rise time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_r		2		μs
Turn-off time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{off}		2.3		μs
Fall time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_f		2		μs
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		f_{CO}		110		kHz
SWITCHING OPERATION (with saturation)							
Turn-on time	$I_F = 20\text{ mA}$	CNY17F-1	t_{on}		3		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_{on}		4.2		μs
		CNY17F-3	t_{on}		4.2		μs
		CNY17F-4	t_{on}		6		μs
Rise time	$I_F = 20\text{ mA}$	CNY17F-1	t_r		2		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_r		3		μs
		CNY17F-3	t_r		3		μs
		CNY17F-4	t_r		4.6		μs
Turn-off time	$I_F = 20\text{ mA}$	CNY17F-1	t_{off}		18		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_{off}		23		μs
		CNY17F-3	t_{off}		23		μs
		CNY17F-4	t_{off}		25		μs
Fall time	$I_F = 20\text{ mA}$	CNY17F-1	t_f		11		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_f		14		μs
		CNY17F-3	t_f		14		μs
		CNY17F-4	t_f		15		μs



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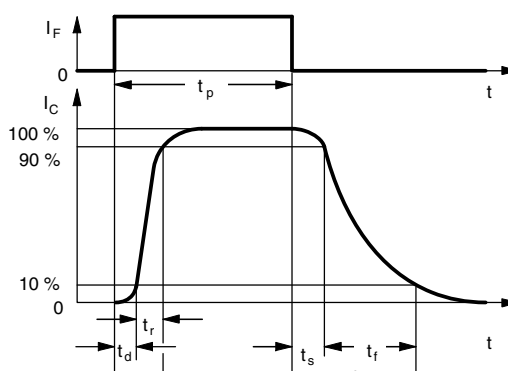
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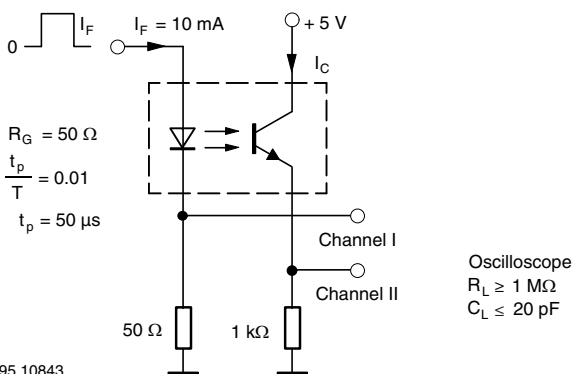
95 10804-3

Fig. 2 - Test Circuit, Non-Saturated Operation



t_p Pulse duration
 t_d Delay time
 t_r Rise time
 $t_{on} (= t_d + t_r)$ Turn-on time
 t_s Storage time
 t_f Fall time
 $t_{off} (= t_s + t_f)$ Turn-off time
 Storage time
 Fall time
 Turn-off time
 96 11698

Fig. 4 - Switching Times



95 10843

Fig. 3 - Test Circuit, Saturated Operation

SAFETY AND INSULATION RATINGS			
PARAMETER	SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS			
Output safety power	P_{SO}	700	mW
Input safety current	I_{SI}	400	mA
Safety temperature	T_{SI}	175	°C
Comparative tracking index	CTI	175	
INSULATION RATED PARAMETERS			
Maximum withstanding isolation voltage	V_{ISO}	5000	V_{RMS}
Maximum transient isolation voltage	V_{IOTM}	8000	V_{peak}
Maximum repetitive peak isolation voltage	V_{IORM}	890	V_{peak}
Insulation resistance	$T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$	$R_{IO} \geq 10^{12}$	Ω
Isolation resistance	$T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$	$R_{IO} \geq 10^{11}$	Ω
Climatic classification (according to IEC 68 part 1)		55/115/21	
Environment (pollution degree in accordance to DIN VDE 0109)		2	
Creepage distance	Standard DIP-4	≥ 7	mm
	SMD	≥ 7	mm
Clearance distance	Standard DIP-4	≥ 8	mm
	SMD	≥ 8	mm
Insulation thickness	DTI	≥ 0.4	mm

Note

- As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

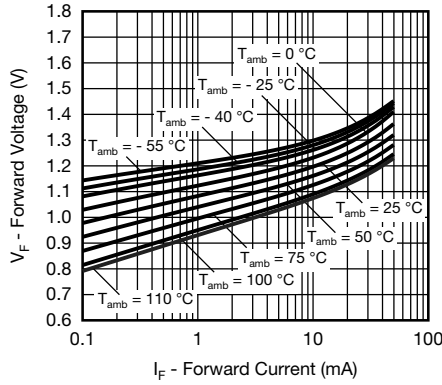


Fig. 5 - Forward Voltage vs. Forward Current

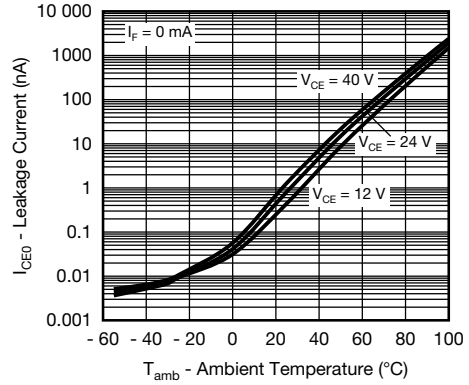


Fig. 8 - Leakage Current vs. Ambient Temperature

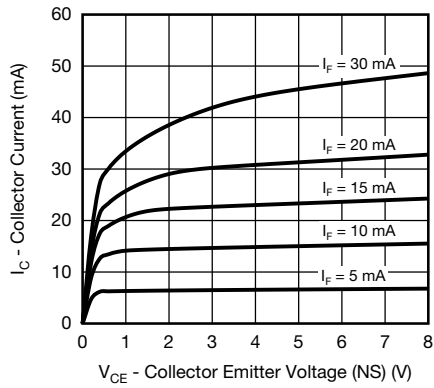


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

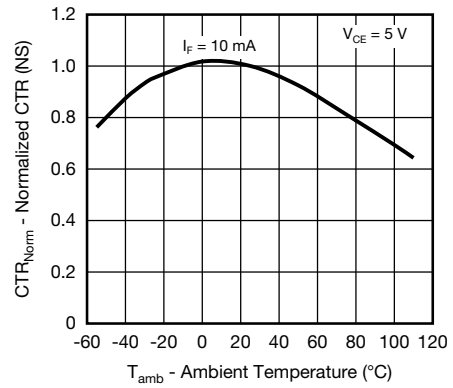


Fig. 9 - Normalized CTR (NS) vs. Ambient Temperature

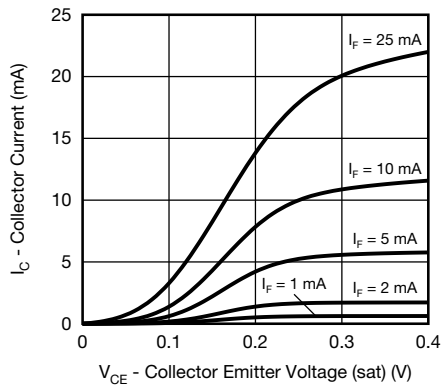


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

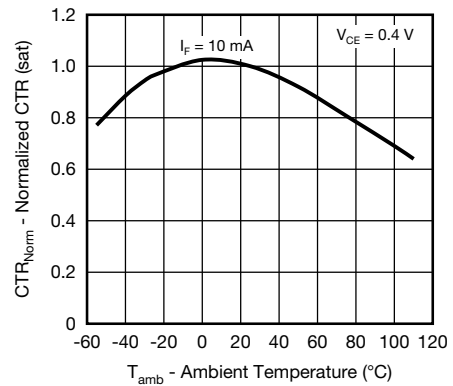


Fig. 10 - Normalized CTR (sat) vs. Ambient Temperature

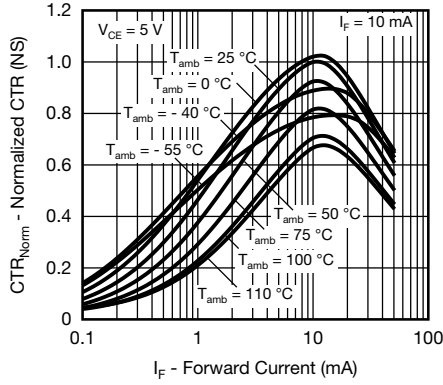


Fig. 11 - Normalized CTR (NS) vs. Forward Current

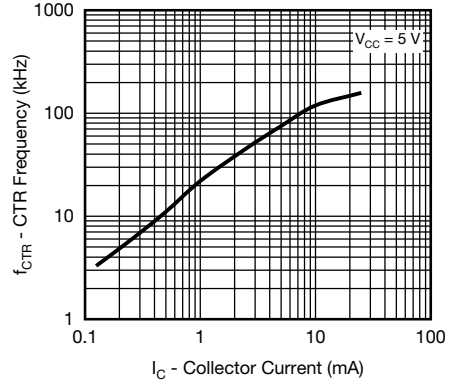


Fig. 14 - CTR -3 dB Frequency vs. Collector Current

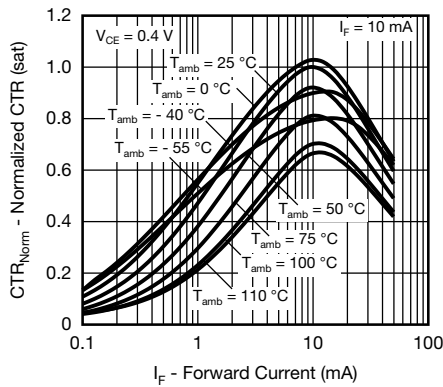


Fig. 12 - Normalized CTR (sat) vs. Forward Current

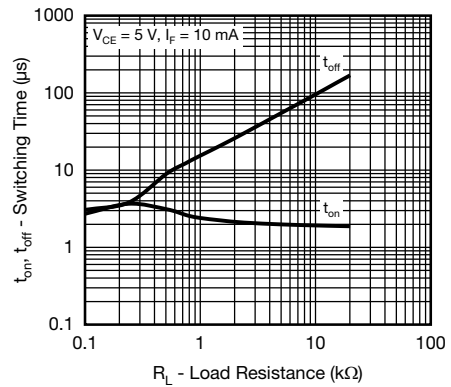


Fig. 15 - Switching Time vs. Load Resistance

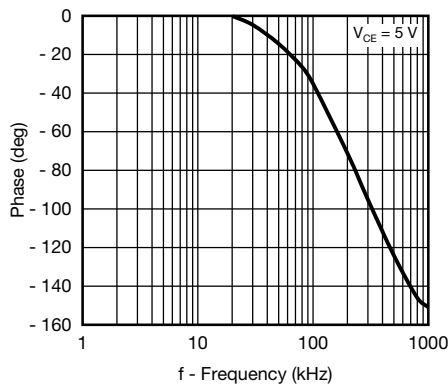


Fig. 13 - CTR Frequency vs. Phase Angle

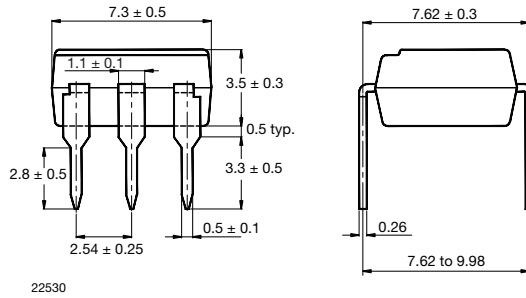
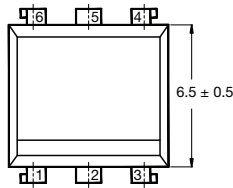


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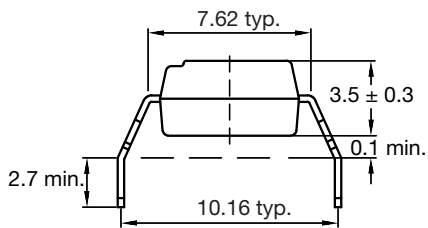
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PACKAGE DIMENSIONS in millimeters

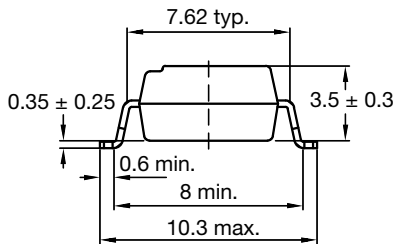


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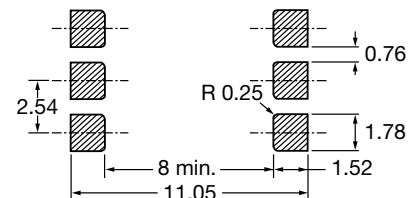
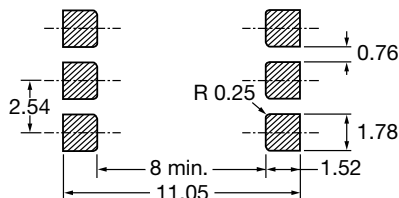
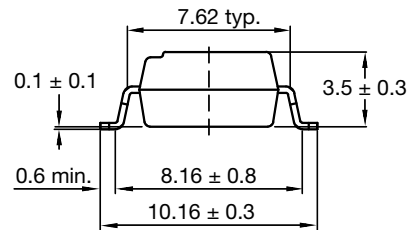
Option 6



Option 7



Option 9



20802-34

PACKAGE MARKING (Example of CNY17F-2x017T)



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



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CNY17F

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TUBE AND TAPE INFORMATION

DEVICES PER TUBE			
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX
DIP-6	50	40	2000

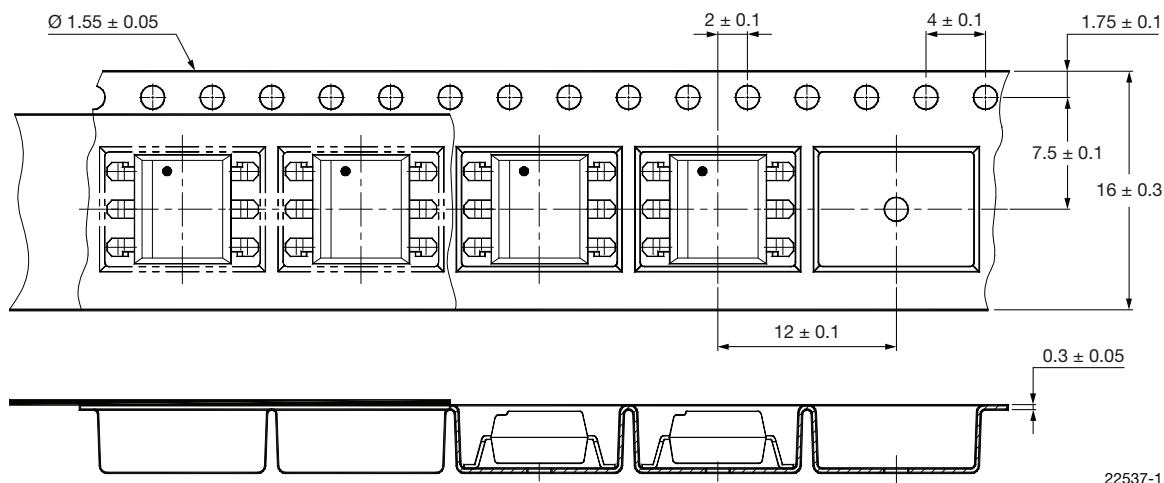


Fig. 16 - Tape and Reel Drawing, 1000 Units per Reel



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